

# **STA7056**

# **3W MONO BRIDGE AMPLIFIER**

**PRODUCT PREVIEW** 

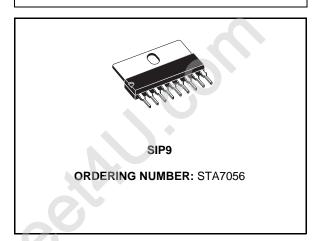
- NO EXTERNAL COMPONENTS
- NO POP AT TURN-ON/OFF
- LOW POWER CONSUMPTION
- SHORT CIRCUIT PROOF

#### **DESCRIPTION**

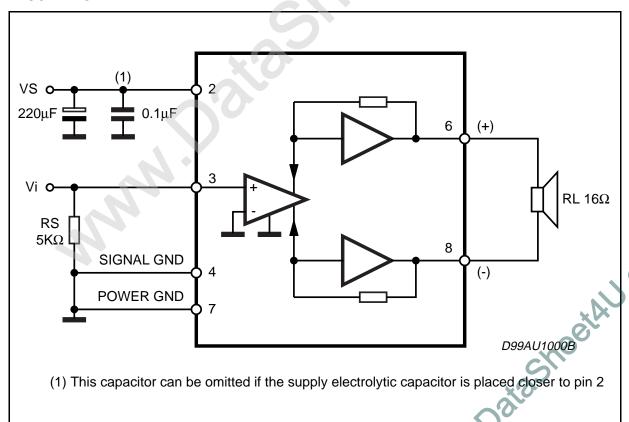
The STA7056 is a mono Bridge Amplifier assembled in single in line 9 pins package.

The STA7056 is specially designed for battery fed portable recorders, radios and TV receivers.

### **BI20II TECHNOLOGY**



#### **BLOCK DIAGRAM**

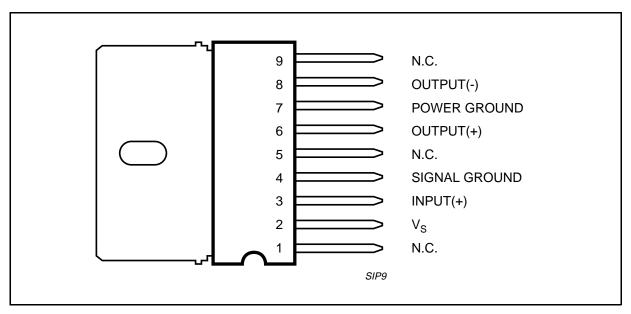


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## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	20	V
lo	Output Peak current (repetitive f ≥ 20Hz)	1	Α
lo	Output Peak current (non repetitive t = 100μs)	1.5	Α
Ptot	Total Power Dissipation (Tcase <70°C)	10	W
Tj,Tstg	Storage and Function Temperature	-40 to 150	°C
T <sub>sc</sub>	Short Circuit Time (the load can be short circuited to all input conditions)	1	hr

### **PIN CONNECTION**



## **THERMAL DATA**

Symbol	Parameter	Value	Unit
Rth j-case	Thermal Resistance Junction-case	8	°C/W
Rth j-amb	Thermal Resistance Junction-ambient	50	°C/W

# **Power Dissipation**

Assume: Vs = 11V;  $RL = 16\Omega$ 

The minimum sine-wave dissipation is 
$$P_d$$
 max =  $\frac{V_S^2}{\pi^2 \cdot R_{L/2}} = 1.52W$ 

The Rth j - amb of the package is 50°C/W.

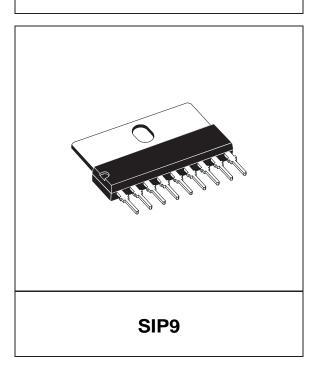
T amb (max) = 
$$150 - 50 \times 1.52 = 74$$
°C

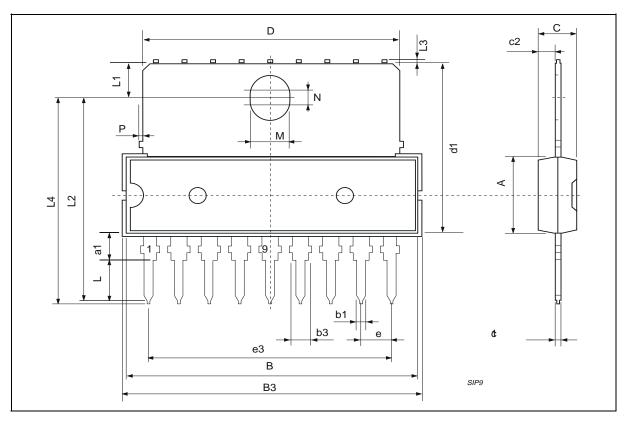
**ELECTRICAL CHARACTERISTICS** (Refer to the test circuit, Vs = 12V; RL =  $16\Omega$ ; Rs =  $50\Omega$ ; f = 1KHz, Tamb =  $25^{\circ}$ C unless otherwise specified.)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Voltage		3		18	V
Iq	Total Quiescent Current	R <sub>L</sub> = ∞		6	8	mA
		RL = 16Ω		10	20	mA
lo	Repetitive Peak Output Current				0.9	Α
Po	Output Power	THD = 10%; R <sub>L</sub> = 16Ω	2.8	3.3		W
		THD = 10%; RL = $8\Omega$		4.5		W
THD	Total Harmonic Distortion	Po = 0.5W		0.25	1	%
G√	Voltage Gain		39	40.5	42	dB
Zin	Input Impedance			100		ΚΩ
li	Input Bias Current			100	300	nA
ΔVο	DC Output Offset Voltage	$Rs = 5K\Omega$			250	mV
SVR	Supply Voltage Rejection	$R_S = 0\Omega$ ; f = 100Hz to 10 KHz; $Vr = 0.2V$	36	50		dB
Vno	Noise Output Voltage	$R_S = 5K\Omega$ ; $f = 20Hz$ to 20 KHz;		180	300	μV

DIM.		mm			inch	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			7.1			0.280
a1	2.7		3	0.106		0.118
В			23			0.90
В3			24.8			0.976
b1		0.5			0.020	
b3	0.85		1.6	0.033		0.063
С		3.3			0.130	
c1		0.43			0.017	
c2		1.32			0.052	
D			21.2			0.835
d1		14.5			0.571	
е		2.54			0.100	
e3		20.32			0.800	
L	3.1			0.122		
L1		3			0.118	
L2		17.6			0.693	
L3			0.25			0.010
L4	17.4		17.85	0.685		0,702
М		3.2			0.126	
N		1			0.039	
Р			0.15			0.006

# OUTLINE AND MECHANICAL DATA





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